Luminescence of undoped and RE doped Na₃Sc₂(PO₄)₃ under high energy irradiation

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Motivation

Phosphates with a NASICON type structure such as $Na_3Sc_2(PO_4)_3$ are known as superionic conductors applied in solid state batteries. Recently it was shown that $Na_3Sc_2(PO_4)_3$ doped with Eu²⁺ demonstrates excellent stability of luminescence in a broad temperature range that makes it promising for lightning applications, e.g. in pcLEDs. The processes of the conversion of high energy irradiation into intrinsic or dopant luminescence has not been studied for this compound so far. Actually, in case of high efficiency of energy transfer from the host to emission centers $Na_3Sc_2(PO_4)_3$ the possible application range of this material could be extended.

Here we present the results of a study of the luminescent properties of undoped and REdoped $Na_3Sc_2(PO_4)_3$ under high energy irradiation.



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Experimental details

 $Na_3Sc_2(PO_4)_3$ (NSP) phosphates, undoped and doped with 0.02 mol% Ce³⁺ or 0.01 mol% Eu³⁺ were synthesized in the reduction atmosphere using a high-temperature solidstate method. Powder X-ray diffraction study revealed that all synthesized samples were single phased with a NASICON-type structure.

The studies of luminescence properties in the energy range 2.5 - 9 eV were performed using laboratory set-ups. The studies under higher excitation energies up to 40 eV were performed at photoluminescence endstation of the FinEstBeAMS beamline of the MAX IV synchrotron radiation facility. Luminescence spectra were also measured at the pulsed cathodoluminescence (CL) setup (E = 120 keV, 0-2 ms).



Wavelength (nm) 280 240 200 160 120 1 - λ_{em} = 240 nm Intensity (a.u.) 6.0 8.0 8.0 2 - λ_{em} = 350 nm 3 - λ_{em} = 560 nm



Luminescence of undoped Na₃Sc₂(PO₄)₃ phosphate





Normalized luminescence spectra of $Na_3Sc_2(PO_4)_3$ at different excitation energies, T = 7 K.

Luminescence excitation spectra of $Na_3Sc_2(PO_4)_3$ at T = 7 K.

Cathodoluminescence spectra of $Na_3Sc_2(PO_4)_3$ at different temperatures and time gates (inset).

> The intrinsic emission is represented with a broad band peaking at 260 nm related to radiative annihilation of self-trapped excitons (STE) with electron components belonging to 3d Sc. Additional broad emission bands peaking at 325 and 530 nm were ascribed to the defects of crystal structure, presumably to the complexes with oxygen vacancies.

- > The onset at 7.1 eV in the excitation spectrum of 260-nm emission band coincides with the fundamental absorption band, while the first peak at 7.45 eV is related to the exciton creation energy. The excitation spectrum of the emission band at 325 nm is represented by a peak at 7.24 eV and a shoulder at 6.4 eV. Its excitation efficiency decreases towards excitonic and fundamental absorption energy region that is related to the competition in energy transfer with the emission centres responsible for the 260-nm band. The intensity in the excitation spectrum of 530-nm emission band drops almost to zero at E_{ex} > 7.5 eV indicating poor energy transfer from the host to this defect emission centre.
- > At low temperature a correlation between cathodo- and photoluminescence (E_{ex} = 45 eV) spectra is observed, while at room temperature the defect-related band at ~490 nm dominates in CL/ spectrum of NSP phosphate. The time-resolved CL spectra shown in the inset indicate the prevalence of slow emission components.



Luminescence of $Na_3Sc_2(PO_4)_3$:Ce³⁺ and $Na_3Sc_2(PO_4)_3$:Eu³⁺ phosphates



Conclusions

The luminescent properties of NASICON-type Na₃Sc₂(PO₄)₃ phosphates, undoped and doped with Ce³⁺ or Eu³⁺, were studied under high-energy excitation for the first time. The origin of the emission bands was determined. Intrinsic emission originating from self-trapped excitons with electron component localized at the 3d Sc states was detected in all compounds. The factors determining the energy transfer efficiency from the host to emission centers were elucidated. The bandgap value was estimated on the basis of excitation spectra analysis to ~8 eV.

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